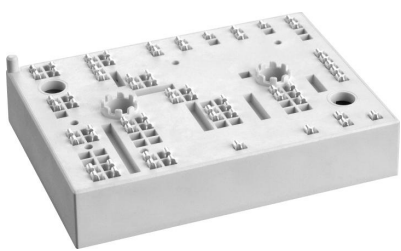


# SKiiP 39AC126V20



MiniSKiiP<sup>®</sup>3

## 3-phase bridge inverter

SKiiP 39AC126V20

Preliminary Data

### Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

### Typical Applications\*

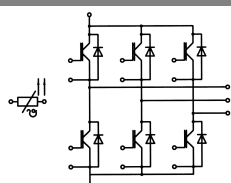
- Inverter up to 45 kVA
- Typical motor power 30 kW

### Remarks

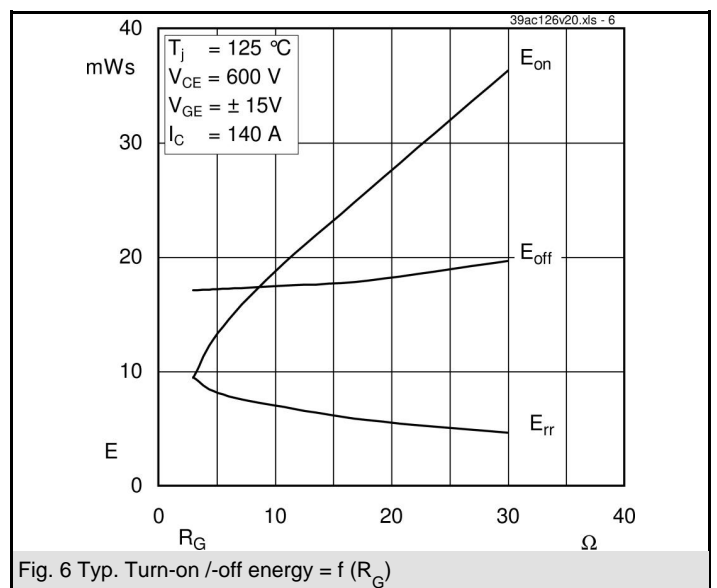
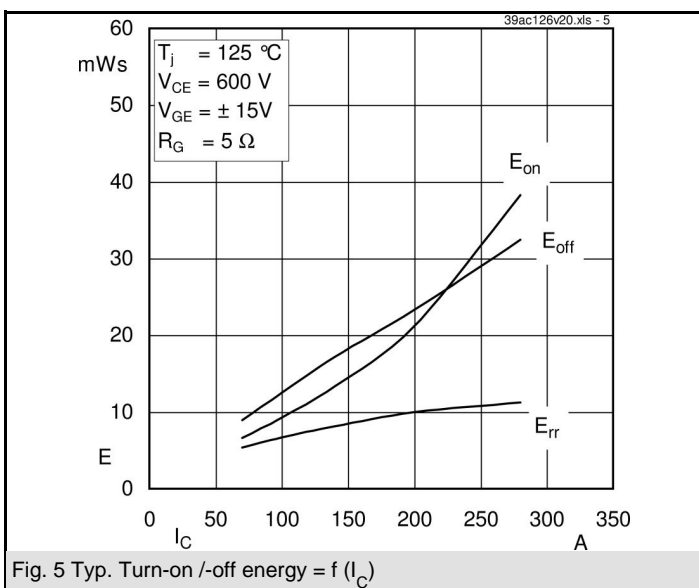
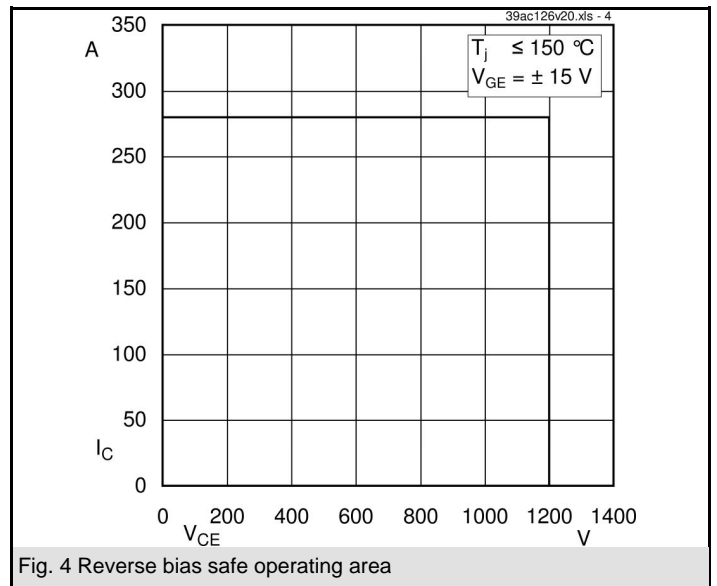
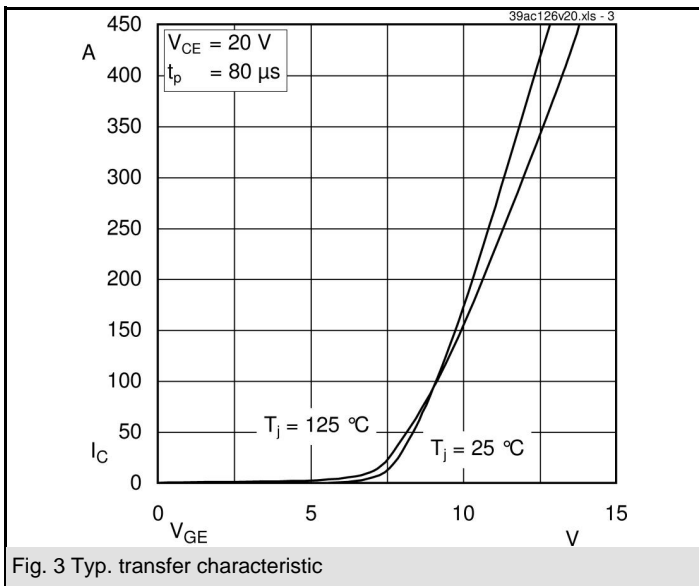
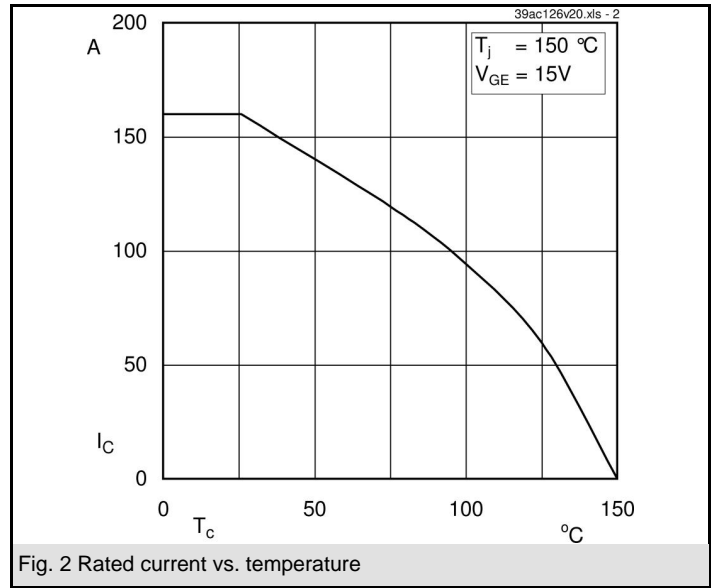
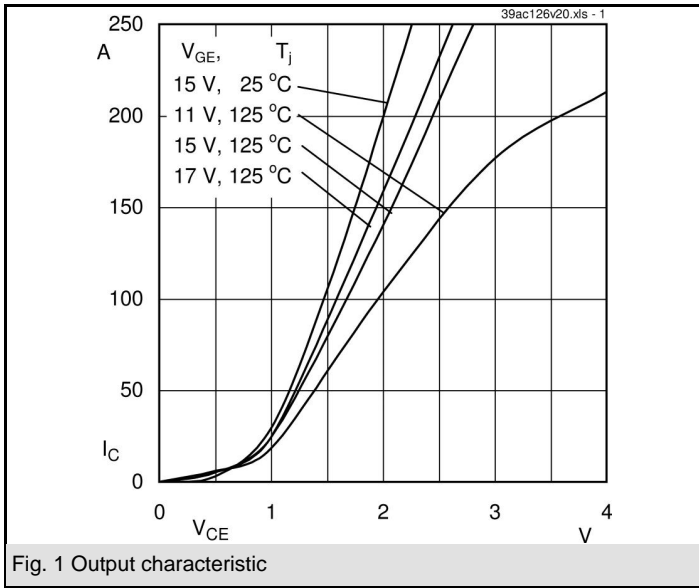
- $V_{CEsat}$ ,  $V_F$  = chip level value

Absolute Maximum Ratings		$T_S = 25\text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter</b>			
$V_{CES}$	$T_S = 25\text{ (70) °C}$ $t_p \leq 1\text{ ms}$	1200	V
$I_C$		157 (118)	A
$I_{CRM}$		280	A
$V_{GES}$		$\pm 20$	V
$T_j$		-40...+150	°C
<b>Diode - Inverter</b>			
$I_F$	$T_S = 25\text{ (70) °C}$ $t_p \leq 1\text{ ms}$	120 (90)	A
$I_{FRM}$		280	A
$T_j$		-40...+150	°C
$I_{tRMS}$	per power terminal (20 A / spring)	160	A
$T_{stg}$	$T_{op} \leq T_{stg}$	-40...+125	°C
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_S = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter</b>					
$V_{CEsat}$	$I_{Cnom} = 140\text{ A}$ , $T_j = 25\text{ (125) °C}$		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 6\text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,2 (1,1)	V
$r_T$	$T_j = 25\text{ (125) °C}$		5 (7,9)	6,4 (9,3)	mΩ
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		11,2		nF
$C_{oes}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		1,9		nF
$C_{res}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		1,5		nF
$R_{th(j-s)}$	per IGBT		0,3		K/W
$t_{d(on)}$	under following conditions		70		ns
$t_r$	$V_{CC} = 600\text{ V}$ , $V_{GE} = \pm 15\text{ V}$		35		ns
$t_{d(off)}$	$I_{Cnom} = 140\text{ A}$ , $T_j = 125\text{ °C}$		480		ns
$t_f$	$R_{Gon} = R_{Goff} = 5\text{ Ω}$		100		ns
$E_{on}$	inductive load		13,3		mJ
$E_{off}$			17,2		mJ
<b>Diode - Inverter</b>					
$V_F = V_{EC}$	$I_{Fnom} = 100\text{ A}$ , $T_j = 25\text{ (125) °C}$		2 (1,8)	2,5 (2,4)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1,1	1,2	V
$r_T$	$T_j = 25\text{ (125) °C}$		9	13	mΩ
$R_{th(j-s)}$	per diode		0,4		K/W
$I_{RRM}$	under following conditions		174		A
$Q_{rr}$	$I_{Fnom} = 140\text{ A}$ , $V_R = 600\text{ V}$		19,5		μC
$E_{rr}$	$V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$		8,1		mJ
	$di_F/dt = 4400\text{ A/μs}$				
<b>Temperature Sensor</b>					
$R_{ts}$	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
<b>Mechanical Data</b>					
m			95		g
$M_s$	Mounting torque	2		2,5	Nm



AC



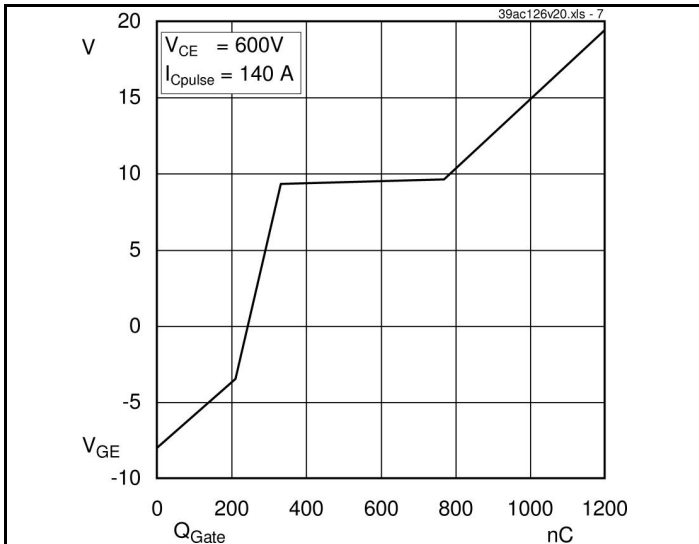


Fig. 7 Typ. gate charge characteristic

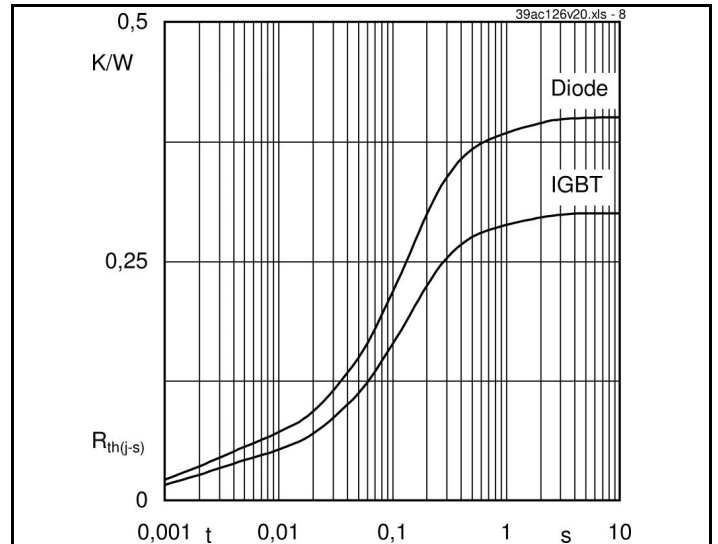


Fig. 8 Typ. thermal impedance

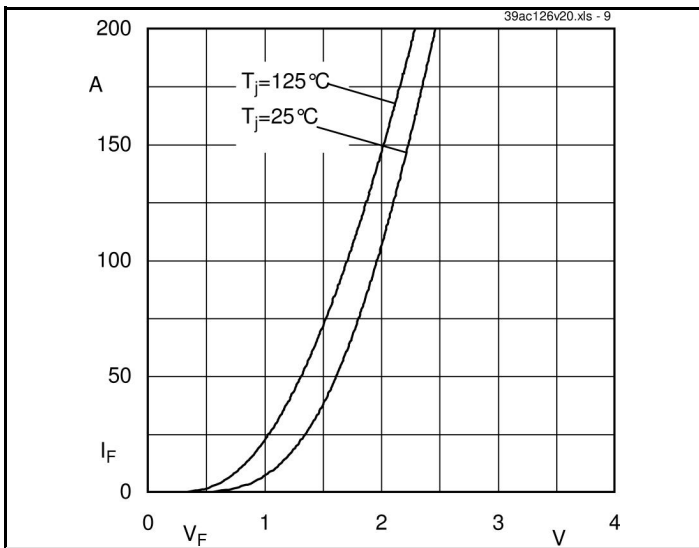
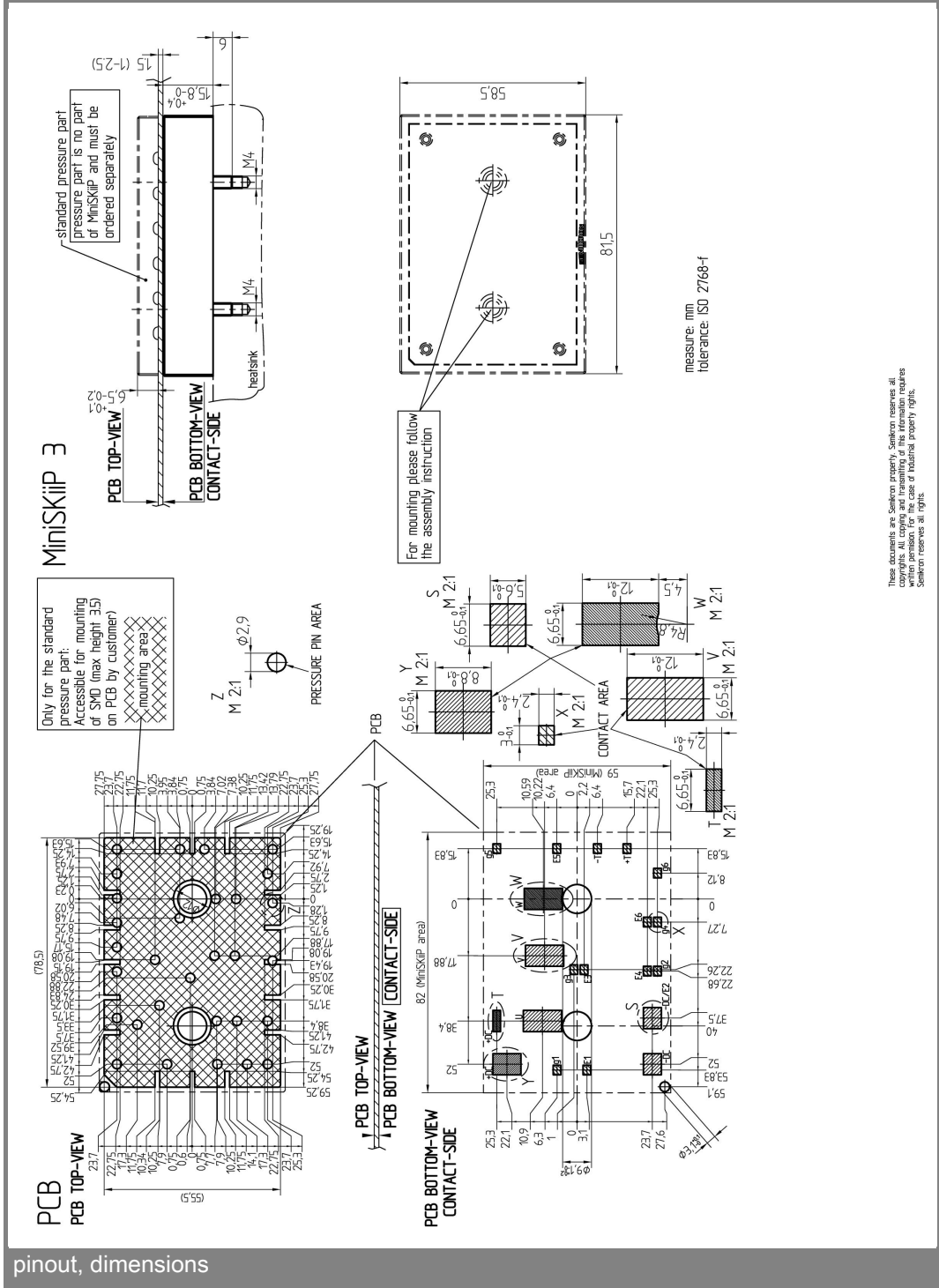
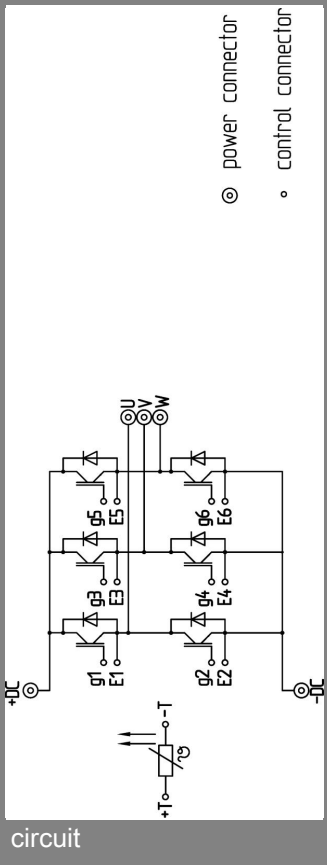


Fig. 9 Typ. freewheeling diode forward characteristic

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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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